

**Amendments to the Claims:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

1 - 2. (Cancelled).

3. (Currently Amended) A method of producing a superconducting wire, comprising ~~the steps of:~~

planarizing a textured metal substrate to have a surface layer extending from a surface thereof to a depth of 300 nm with a crystal axis offset relative to an orientation axis by at most 25°, and a surface roughness  $R_{P-V}$  of at most 150 nm;

thermally treating said textured metal substrate at a temperature of 500°C to 800°C in a reduced or vacuumed atmosphere at least once; and

depositing a superconducting layer on said textured metal substrate ~~planarized that has~~ been thermally treated.

4. - 5. (Cancelled).

6. (Currently Amended) The method according to claim 3, wherein ~~the step of~~ planarizing said textured metal substrate is performed by at least one of: mirror finished rolling; mechanochemistry; electrolytic polishing; and chemical polishing.

7. - 8. (Cancelled).

9. (Currently Amended) ~~The method according to claim 3, further comprising the steps of:~~ A method of producing a superconducting wire, comprising:

planarizing a textured metal substrate to have a surface layer extending from a surface thereof to a depth of 300 nm with a crystal axis offset relative to an orientation axis by at most 25°, and a surface roughness  $R_{P-V}$  of less than or equal to 150 nm;

thermally treating said textured metal substrate at a temperature of 500°C to 800°C in a reduced or vacuumed atmosphere at least once; and

depositing an intermediate layer on said textured metal substrate; and

depositing a ~~said~~ superconducting layer on said textured metal substrate that has been thermally treated.

10. - 11. (Cancelled).

12. (Currently Amended) The method according to claim 9, wherein ~~the step of~~ planarizing said textured metal substrate is performed by at least one of: mirror finished rolling; mechanochemistry; electrolytic polishing; and chemical polishing.

13. - 14. (Cancelled).

15. (Previously Presented) The method according to claim 3, wherein planarizing the textured metal substrate comprises planarizing the textured metal substrate such that the crystal axis is offset relative to the orientation axis by at most 12°.

16. (Previously Presented) The method according to claim 3, wherein planarizing the textured metal substrate comprises planarizing the textured metal substrate such that the crystal axis is offset relative to the orientation axis by at most 10°.

17. (New) The method according to claim 9, wherein planarizing the textured metal substrate comprises planarizing the textured metal substrate such that the crystal axis is offset relative to the orientation axis by at most 12°.

18. (New) The method according to claim 9, wherein planarizing the textured metal substrate comprises planarizing the textured metal substrate such that the crystal axis is offset relative to the orientation axis by at most 10°.

19. (New) The method according to claim 3, wherein the thermally treating said textured metal substrate occurs at a temperature of 600°C to 700°C in a reduced or vacuumed atmosphere at least once.

20. (New) The method according to claim 9, wherein the thermally treating said textured metal substrate occurs at a temperature of 600°C to 700°C in a reduced or vacuumed atmosphere at least once.

21. (New) The method according to claim 3, wherein the vacuumed atmosphere is at a pressure of less than  $1.33 \times 10^2$  Pa.

22. (New) The method according to claim 3, wherein the thermal treatment occurs for at least 2 minutes.